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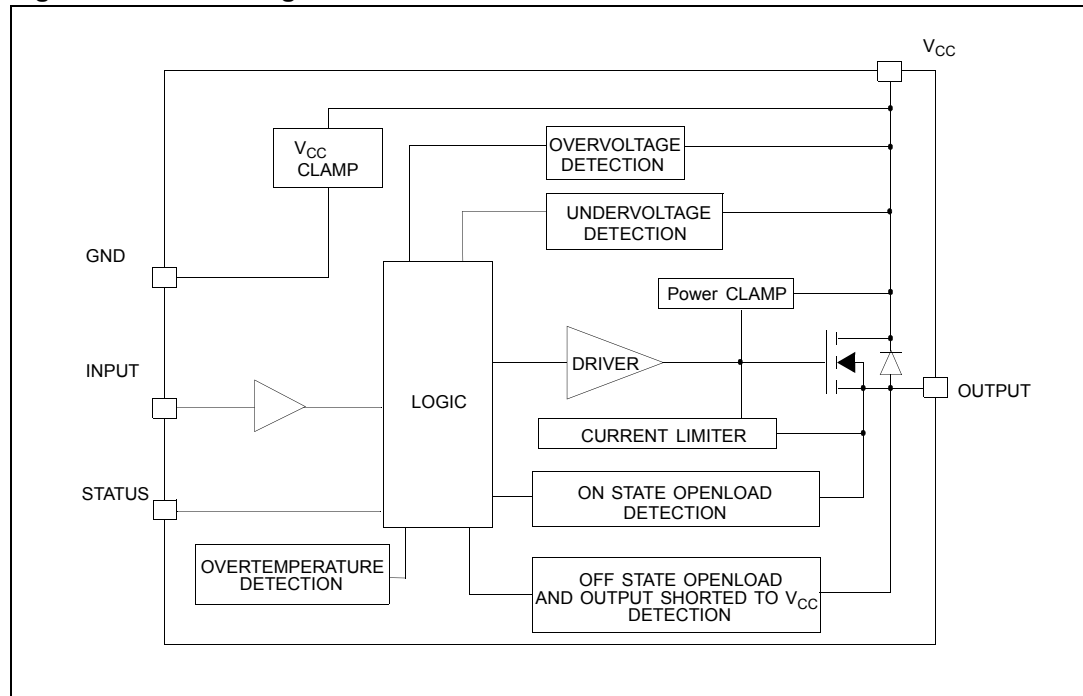
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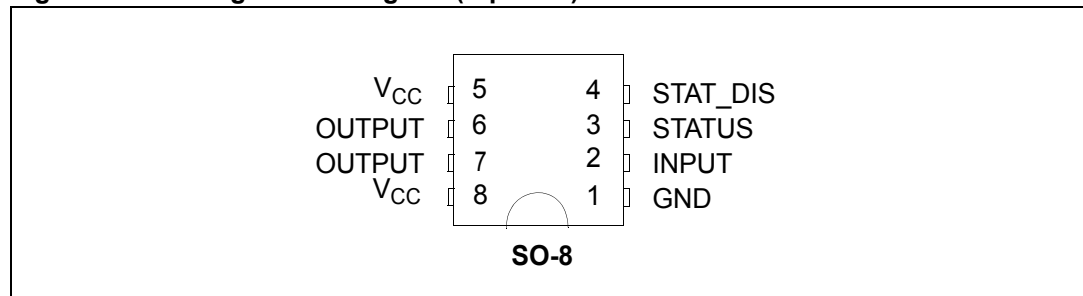
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## 1 Block diagram and pin description

**Figure 1. Block diagram**



**Figure 2. Configuration diagram (top view)**

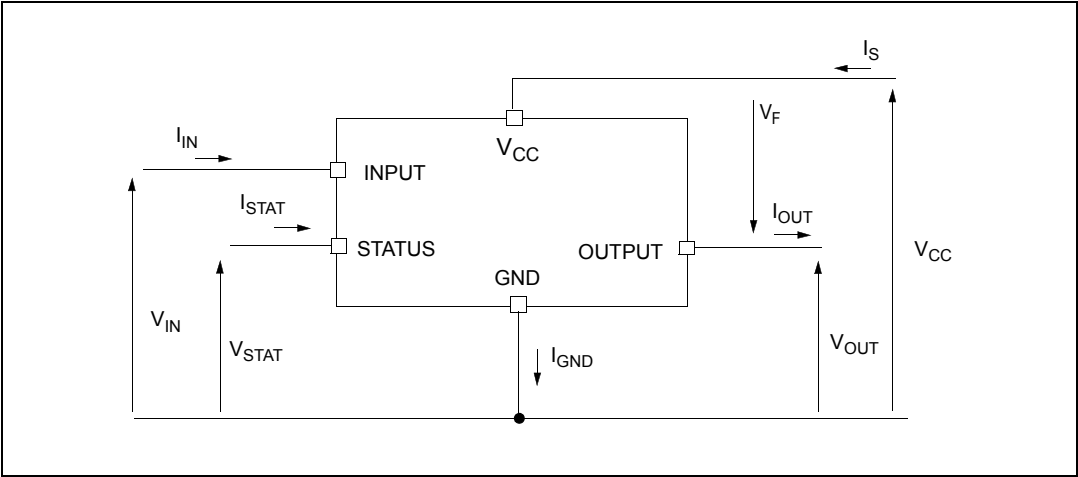


**Table 2. Suggested connections for unused and not connected pins**

| Connection/pin | Status | N.C. | Output | Input                          |
|----------------|--------|------|--------|--------------------------------|
| Floating       | X      | X    | X      | X                              |
| To ground      |        | X    |        | Through 10 K $\Omega$ resistor |

# 2 Electrical specifications

Figure 3. Current and voltage conventions



## 2.1 Absolute maximum ratings

Stress values that exceed those listed in the “Absolute maximum ratings” table can cause permanent damage to the device. These are stress ratings only, and operation of the device at these, or any other conditions greater than those, indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics sure program and other relevant quality documents.

Table 3. Absolute maximum ratings

| Symbol     | Parameter                                                                                 | Value              | Unit |
|------------|-------------------------------------------------------------------------------------------|--------------------|------|
| $V_{CC}$   | DC supply voltage                                                                         | 41                 | V    |
| $-V_{CC}$  | Reverse DC supply voltage                                                                 | - 0.3              | V    |
| $-I_{gnd}$ | DC reverse ground pin current                                                             | - 200              | mA   |
| $I_{OUT}$  | DC output current                                                                         | Internally limited | A    |
| $-I_{OUT}$ | Reverse DC output current                                                                 | - 6                | A    |
| $I_{IN}$   | DC input current                                                                          | +/- 10             | mA   |
| $I_{STAT}$ | DC status current                                                                         | +/- 10             | mA   |
| $V_{ESD}$  | Electrostatic discharge<br>(human body model: $R=1.5\text{ K}\Omega$ ; $C=100\text{pF}$ ) |                    |      |
|            | - Input                                                                                   | 4000               | V    |
|            | - Status                                                                                  | 4000               | V    |
|            | - Output                                                                                  | 5000               | V    |
|            | - $V_{CC}$                                                                                | 5000               | V    |

**Table 3. Absolute maximum ratings (continued)**

| Symbol    | Parameter                                                                                                                                        | Value              | Unit             |
|-----------|--------------------------------------------------------------------------------------------------------------------------------------------------|--------------------|------------------|
| $E_{MAX}$ | Maximum switching energy<br>( $L=1.3\text{mH}$ ; $R_L=0\Omega$ ; $V_{bat}=13.5\text{V}$ ; $T_{jstart}=150^\circ\text{C}$ ;<br>$I_L=10\text{A}$ ) | 90                 | mJ               |
| $P_{tot}$ | Power dissipation $T_C=25^\circ\text{C}$                                                                                                         | 4.2                | W                |
| $T_j$     | Junction operating temperature                                                                                                                   | Internally limited | $^\circ\text{C}$ |
| $T_{stg}$ | Storage temperature                                                                                                                              | - 55 to 150        | $^\circ\text{C}$ |

## 2.2 Thermal data

**Table 4. Thermal data**

| Symbol         | Parameter                           | Max. value        |                   | Unit               |
|----------------|-------------------------------------|-------------------|-------------------|--------------------|
| $R_{thj-case}$ | Thermal resistance junction-case    | 1.7               |                   | $^\circ\text{C/W}$ |
| $R_{thj-amb}$  | Thermal resistance junction-ambient | 93 <sup>(1)</sup> | 82 <sup>(2)</sup> | $^\circ\text{C/W}$ |

1. When mounted on a standard single-sided FR-4 board with  $0.5\text{cm}^2$  of Cu (at least  $35\mu\text{m}$  thick) connected to all  $V_{CC}$  pins. Horizontal mounting and no artificial air flow.
2. When mounted on a standard single-sided FR-4 board with  $2\text{cm}^2$  of Cu (at least  $35\mu\text{m}$  thick) connected to all  $V_{CC}$  pins. Horizontal mounting and no artificial air flow.

## 2.3 Electrical characteristics

Values specified in this section are for  $8\text{ V} < V_{CC} < 36\text{ V}$ ;  $-40\text{ }^\circ\text{C} < T_j < 150\text{ }^\circ\text{C}$ , unless otherwise specified.

**Table 5. Power**

| Symbol        | Parameter                        | Test conditions                                                                                                                                                                                                                                      | Min. | Typ.          | Max.            | Unit                                 |
|---------------|----------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|---------------|-----------------|--------------------------------------|
| $V_{CC}$      | Operating supply voltage         |                                                                                                                                                                                                                                                      | 5.5  | 13            | 36              | V                                    |
| $V_{USD}$     | Undervoltage shutdown            |                                                                                                                                                                                                                                                      | 3    | 4             | 5.5             | V                                    |
| $V_{USDhyst}$ | Undervoltage shutdown hysteresis |                                                                                                                                                                                                                                                      |      | 0.5           |                 | V                                    |
| $V_{OV}$      | Overvoltage shutdown             |                                                                                                                                                                                                                                                      | 36   |               |                 | V                                    |
| $R_{ON}$      | On-state resistance              | $I_{OUT}=2\text{ A}$ ; $T_j=25\text{ }^\circ\text{C}$ ; $V_{CC}>8\text{ V}$<br>$I_{OUT}=2\text{ A}$ ; $V_{CC}>8\text{ V}$                                                                                                                            |      |               | 55<br>110       | $\text{m}\Omega$<br>$\text{m}\Omega$ |
| $I_S$         | Supply current                   | Off-state; $V_{CC}=13\text{ V}$ ; $V_{IN}=V_{OUT}=0\text{ V}$<br>Off-state; $V_{CC}=13\text{ V}$ ; $V_{IN}=V_{OUT}=0\text{ V}$ ;<br>$T_j=25\text{ }^\circ\text{C}$<br>On-state; $V_{CC}=13\text{ V}$ ; $V_{IN}=5\text{ V}$ ;<br>$I_{OUT}=0\text{ A}$ |      | 10<br>10<br>2 | 25<br>20<br>3.5 | $\mu\text{A}$<br>$\mu\text{A}$<br>mA |
| $I_{L(off1)}$ | Off-state output current         | $V_{IN}=V_{OUT}=0\text{ V}$                                                                                                                                                                                                                          | 0    |               | 50              | $\mu\text{A}$                        |
| $I_{L(off2)}$ | Off-state output current         | $V_{IN}=0\text{V}$ ; $V_{OUT}=3.5\text{ V}$                                                                                                                                                                                                          | -75  |               | 0               | $\mu\text{A}$                        |

**Table 5. Power (continued)**

| Symbol        | Parameter                | Test conditions                                   | Min. | Typ. | Max. | Unit    |
|---------------|--------------------------|---------------------------------------------------|------|------|------|---------|
| $I_{L(off3)}$ | Off-state output current | $V_{IN}=V_{OUT}=0$ V; $V_{CC}=13$ V; $T_j=125$ °C |      |      | 5    | $\mu$ A |
| $I_{L(off4)}$ | Off-state output current | $V_{IN}=V_{OUT}=0$ V; $V_{CC}=13$ V; $T_j=25$ °C  |      |      | 3    | $\mu$ A |

**Table 6. Switching ( $V_{CC}=13$  V)**

| Symbol                | Parameter              | Test conditions                                                   | Min. | Typ.                 | Max. | Unit       |
|-----------------------|------------------------|-------------------------------------------------------------------|------|----------------------|------|------------|
| $t_{d(on)}$           | Turn-on delay time     | $R_L=6.5$ $\Omega$ from $V_{IN}$ rising edge to $V_{OUT}=1.3$ V   | -    | 40                   | -    | $\mu$ s    |
| $t_{d(off)}$          | Turn-off delay time    | $R_L=6.5$ $\Omega$ from $V_{IN}$ falling edge to $V_{OUT}=11.7$ V | -    | 30                   | -    | $\mu$ s    |
| $dV_{OUT}/dt_{(on)}$  | Turn-on voltage slope  | $R_L=6.5$ $\Omega$ from $V_{OUT}=1.3$ V to $V_{OUT}=10.4$ V       | -    | See relative diagram | -    | V/ $\mu$ s |
| $dV_{OUT}/dt_{(off)}$ | Turn-off voltage slope | $R_L=6.5$ $\Omega$ from $V_{OUT}=11.7$ V to $V_{OUT}=1.3$ V       | -    | See relative diagram | -    | V/ $\mu$ s |

**Table 7. Input pin**

| Symbol     | Parameter                | Test conditions                 | Min. | Typ.        | Max. | Unit    |
|------------|--------------------------|---------------------------------|------|-------------|------|---------|
| $V_{IL}$   | Input low level          |                                 |      |             | 1.25 | V       |
| $I_{IL}$   | Low level input current  | $V_{IN}=1.25$ V                 | 1    |             |      | $\mu$ A |
| $V_{IH}$   | Input high level         |                                 | 3.25 |             |      | V       |
| $I_{IH}$   | High level input current | $V_{IN}=3.25$ V                 |      |             | 10   | $\mu$ A |
| $V_{hyst}$ | Input hysteresis voltage |                                 | 0.5  |             |      | V       |
| $V_{ICL}$  | Input clamp voltage      | $I_{IN}=1$ mA<br>$I_{IN}=-1$ mA | 6    | 6.8<br>-0.7 | 8    | V<br>V  |

**Table 8.  $V_{CC}$  output diode**

| Symbol | Parameter          | Test conditions                | Min. | Typ. | Max. | Unit |
|--------|--------------------|--------------------------------|------|------|------|------|
| $V_F$  | Forward on voltage | $-I_{OUT}=1.4$ A; $T_j=150$ °C |      |      | 0.6  | V    |

**Table 9. Status pin**

| Symbol      | Parameter                 | Test conditions                  | Min. | Typ. | Max. | Unit    |
|-------------|---------------------------|----------------------------------|------|------|------|---------|
| $V_{STAT}$  | Status low output voltage | $I_{STAT}=1.6$ mA                |      |      | 0.5  | V       |
| $I_{LSTAT}$ | Status leakage current    | Normal operation; $V_{STAT}=5$ V |      |      | 10   | $\mu$ A |

Table 9. Status pin (continued)

| Symbol     | Parameter                    | Test conditions                                   | Min. | Typ.        | Max. | Unit   |
|------------|------------------------------|---------------------------------------------------|------|-------------|------|--------|
| $C_{STAT}$ | Status pin input capacitance | Normal operation; $V_{STAT}=5\text{ V}$           |      |             | 100  | pF     |
| $V_{SCL}$  | Status clamp voltage         | $I_{STAT}=1\text{ mA}$<br>$I_{STAT}=-1\text{ mA}$ | 6    | 6.8<br>-0.7 | 8    | V<br>V |

Table 10. Protections<sup>(1)</sup>

| Symbol      | Parameter                          | Test conditions                                              | Min.        | Typ.        | Max.        | Unit   |
|-------------|------------------------------------|--------------------------------------------------------------|-------------|-------------|-------------|--------|
| $T_{TSD}$   | Shutdown temperature               |                                                              | 150         | 175         | 200         | °C     |
| $T_R$       | Reset temperature                  |                                                              | 135         |             |             | °C     |
| $T_{hyst}$  | Thermal hysteresis                 |                                                              | 7           | 15          |             | °C     |
| $t_{SDL}$   | Status delay in overload condition | $T_j > T_{jsh}$                                              |             |             | 20          | ms     |
| $I_{lim}$   | Current limitation                 | $5.5\text{ V} < V_{CC} < 36\text{ V}$                        | 6           | 10          | 12<br>12    | A<br>A |
| $V_{demag}$ | Turn-off output clamp voltage      | $I_{OUT}=2\text{ A}$ ; $V_{IN}=0\text{ V}$ ; $L=6\text{ mH}$ | $V_{CC}-41$ | $V_{CC}-48$ | $V_{CC}-55$ | V      |

1. To ensure long term reliability under heavy overload or short circuit conditions, protection and related diagnostic signals must be used together with a proper software strategy. If the device operates under abnormal conditions this software must limit the duration and number of activation cycles.

Table 11. Open-load detection

| Symbol         | Parameter                                       | Test conditions      | Min. | Typ. | Max. | Unit |
|----------------|-------------------------------------------------|----------------------|------|------|------|------|
| $I_{OL}$       | Open-load on-state detection threshold          | $V_{IN}=5\text{ V}$  | 0.6  | 0.9  | 1.2  | A    |
| $t_{DOL(on)}$  | Open-load on-state detection delay              | $I_{OUT}=0\text{ A}$ |      |      | 200  | μs   |
| $V_{OL}$       | Open-load off-state voltage detection threshold | $V_{IN}=0\text{ V}$  | 1.5  | 2.5  | 3.5  | V    |
| $t_{DOL(off)}$ | Open-load detection delay at turn-off           |                      |      |      | 1000 | μs   |



Figure 4. Status timings

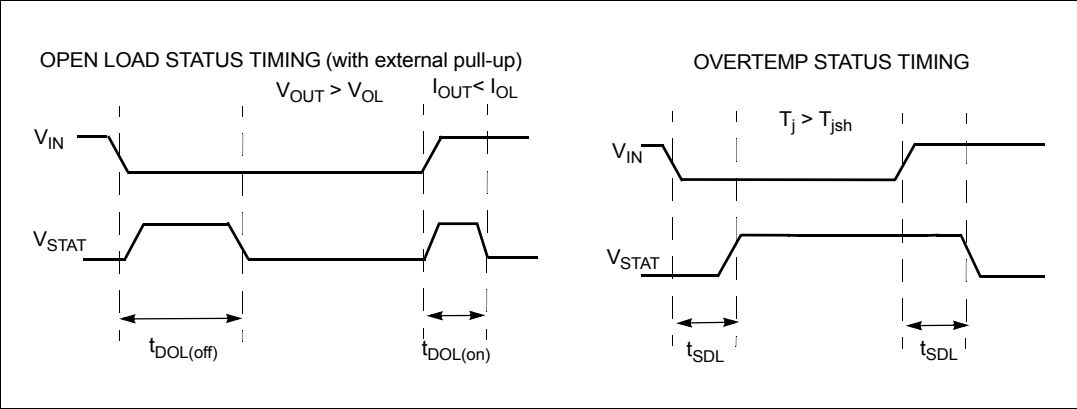


Figure 5. Switching time waveforms

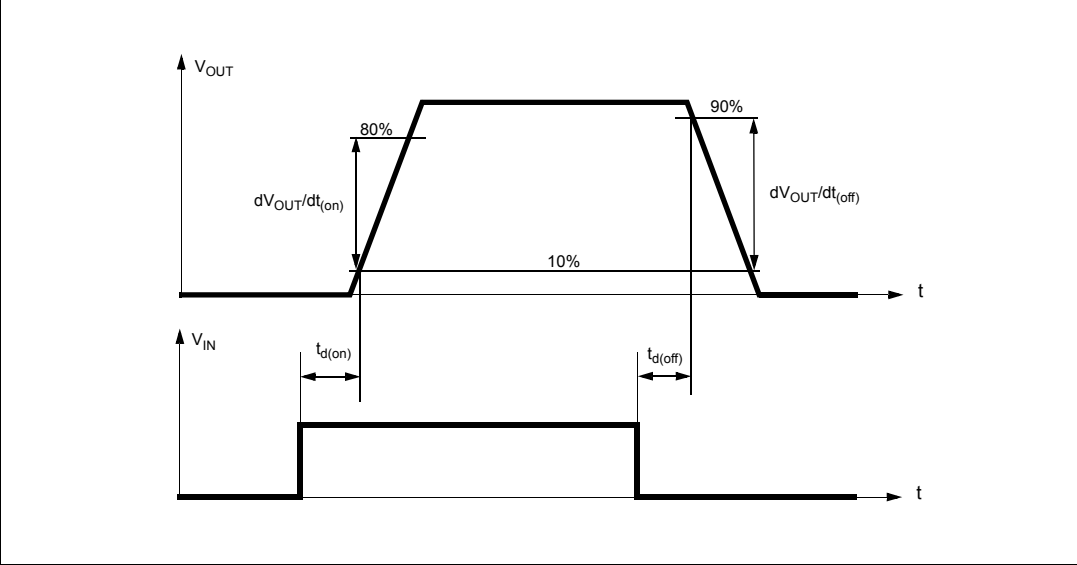


Table 12. Truth table

| Conditions         | Input | Output | Status              |
|--------------------|-------|--------|---------------------|
| Normal operation   | L     | L      | H                   |
|                    | H     | H      | H                   |
| Current limitation | L     | L      | H                   |
|                    | H     | X      | $(T_j < T_{TSD})$ H |
|                    | H     | X      | $(T_j > T_{TSD})$ L |
| Overtemperature    | L     | L      | H                   |
|                    | H     | L      | L                   |
| Undervoltage       | L     | L      | X                   |
|                    | H     | L      | X                   |
| Overvoltage        | L     | L      | H                   |
|                    | H     | L      | H                   |

Table 12. Truth table

| Conditions                | Input | Output | Status |
|---------------------------|-------|--------|--------|
| Output voltage > $V_{OL}$ | L     | H      | L      |
|                           | H     | H      | H      |
| Output current < $I_{OL}$ | L     | L      | H      |
|                           | H     | H      | L      |

Table 13. Electrical transient requirements on  $V_{CC}$  pin (part 1/3)

| ISO T/R 7637/1<br>test pulse | Test levels |         |         |         |                         |
|------------------------------|-------------|---------|---------|---------|-------------------------|
|                              | I           | II      | III     | IV      | Delays and impedance    |
| 1                            | -25 V       | -50 V   | -75 V   | -100 V  | 2 ms 10 $\Omega$        |
| 2                            | +25 V       | +50 V   | +75 V   | +100 V  | 0.2 ms 10 $\Omega$      |
| 3a                           | -25 V       | -50 V   | -100 V  | -150 V  | 0.1 $\mu$ s 50 $\Omega$ |
| 3b                           | +25 V       | +50 V   | +75 V   | +100 V  | 0.1 $\mu$ s 50 $\Omega$ |
| 4                            | -4 V        | -5 V    | -6 V    | -7 V    | 100 ms, 0.01 $\Omega$   |
| 5                            | +26.5 V     | +46.5 V | +66.5 V | +86.5 V | 400 ms, 2 $\Omega$      |

Table 14. Electrical transient requirements on  $V_{CC}$  pin (part 2/3)

| ISO T/R 7637/1<br>test pulse | Test levels results |    |     |    |
|------------------------------|---------------------|----|-----|----|
|                              | I                   | II | III | IV |
| 1                            | C                   | C  | C   | C  |
| 2                            | C                   | C  | C   | C  |
| 3a                           | C                   | C  | C   | C  |
| 3b                           | C                   | C  | C   | C  |
| 4                            | C                   | C  | C   | C  |
| 5                            | C                   | E  | E   | E  |

Table 15. Electrical transient requirements on  $V_{CC}$  pin (part 3/3)

| Class | Contents                                                                                                                                                                |
|-------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| C     | All functions of the device are performed as designed after exposure to disturbance.                                                                                    |
| E     | One or more functions of the device is not performed as designed after exposure to disturbance and cannot be returned to proper operation without replacing the device. |

The figure displays six timing diagrams for the MCP3002, illustrating its behavior under different conditions:

- NORMAL OPERATION:** Shows the relationship between the INPUT signal, the resulting LOAD VOLTAGE, and the STATUS signal. The STATUS signal is active-low, indicating a valid conversion when it is low.
- UNDERVOLTAGE:** Illustrates the device's response to a low supply voltage ( $V_{CC}$ ). The undervoltage threshold is marked as  $V_{USD}$ , and the hysteresis voltage is  $V_{USDhyst}$ . During this condition, the STATUS signal is set to an "undefined" state.
- OVERVOLTAGE:** Shows the response to a high supply voltage ( $V_{CC}$ ). The overvoltage threshold is  $V_{OV}$ . The regions are labeled  $V_{CC} < V_{OV}$  and  $V_{CC} > V_{OV}$ .
- OPEN LOAD with external pull-up:** Demonstrates the output voltage ( $V_{OUT}$ ) and STATUS signal when an external pull-up resistor is present. The open-load voltage is  $V_{OL}$ , and the condition  $V_{OUT} > V_{OL}$  is indicated.
- OPEN LOAD without external pull-up:** Shows the output voltage and STATUS signal when no external pull-up is connected. The STATUS signal transitions to high when the load is open.
- OVERTEMPERATURE:** Illustrates the response to excessive temperature. The junction temperature ( $T_J$ ) is compared against the shutdown threshold  $T_{TSD}$  and the reset threshold  $T_R$ . When  $T_J$  exceeds  $T_{TSD}$ , the device enters shutdown, and the STATUS signal is set to high.

2.4 Electrical characteristics curves

Figure 7. Off-state output current

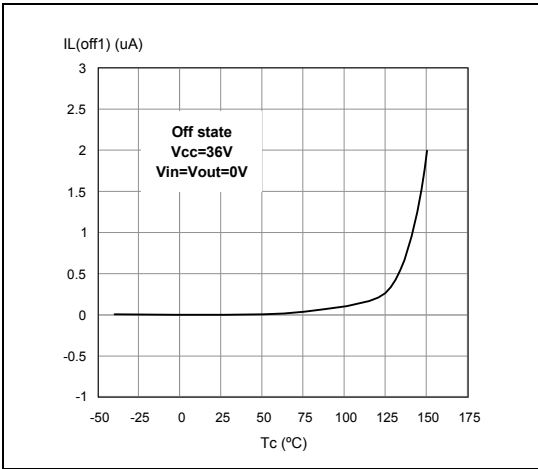


Figure 8. High level input current

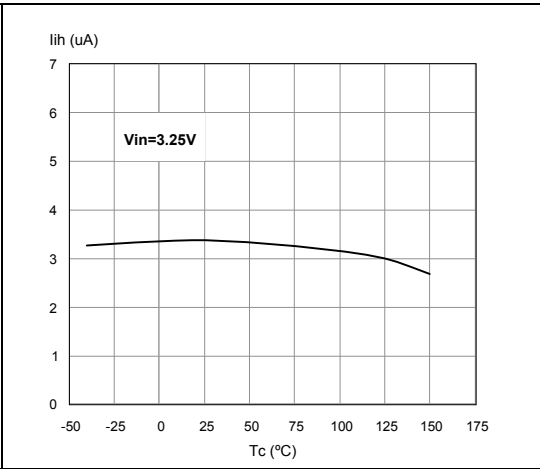


Figure 9. Input clamp voltage

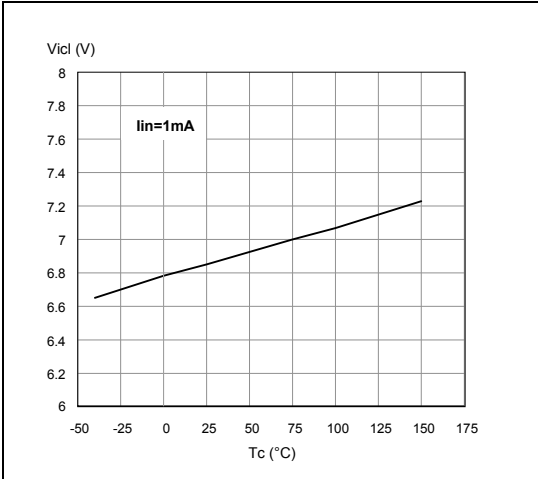


Figure 10. Status leakage current

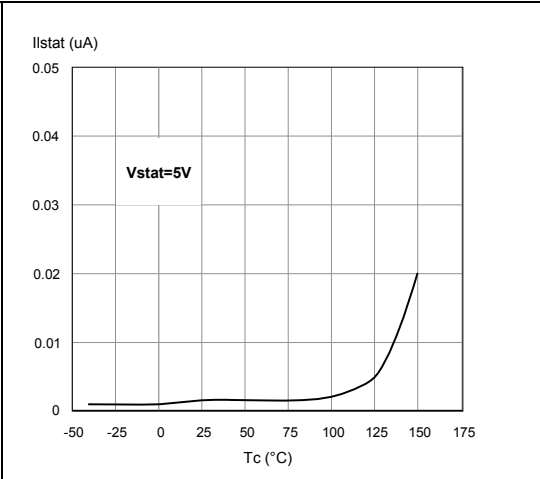


Figure 11. Status low output voltage

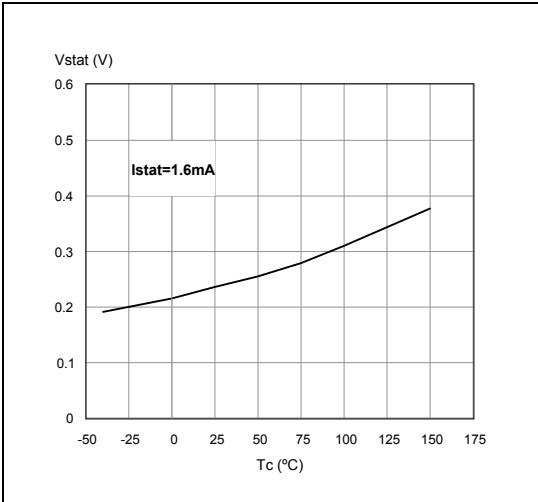


Figure 12. Status clamp voltage

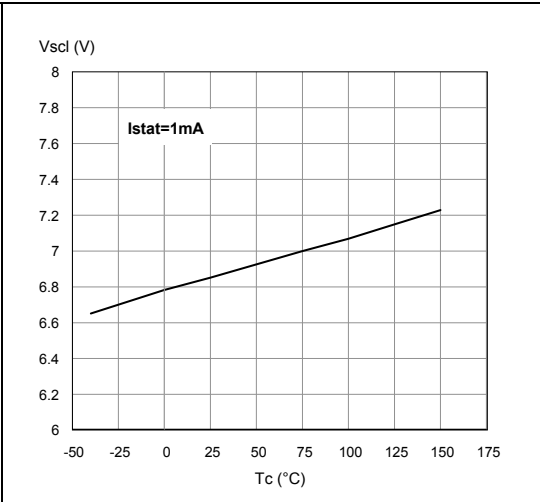


Figure 13. On-state resistance vs  $T_{case}$

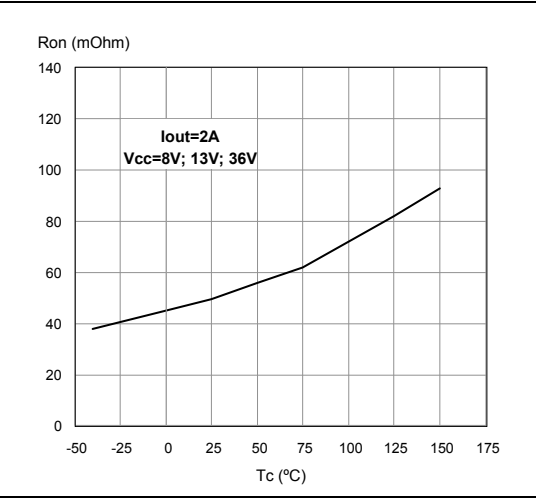


Figure 14. On-state resistance vs  $V_{CC}$

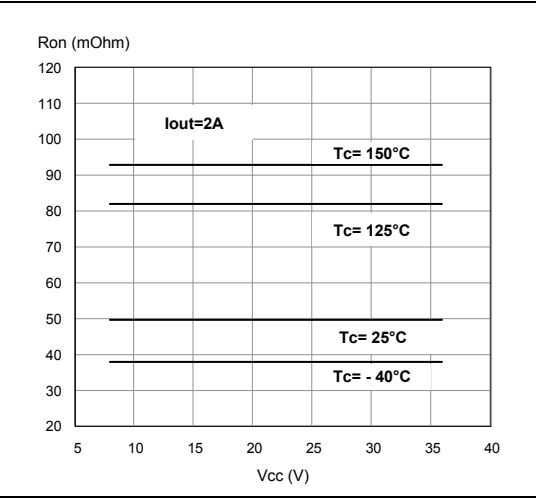


Figure 15. Open-load on-state detection threshold

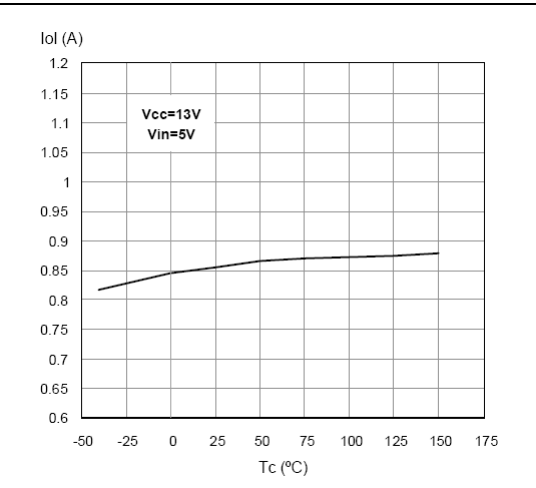


Figure 16. Open-load off-state voltage detection threshold

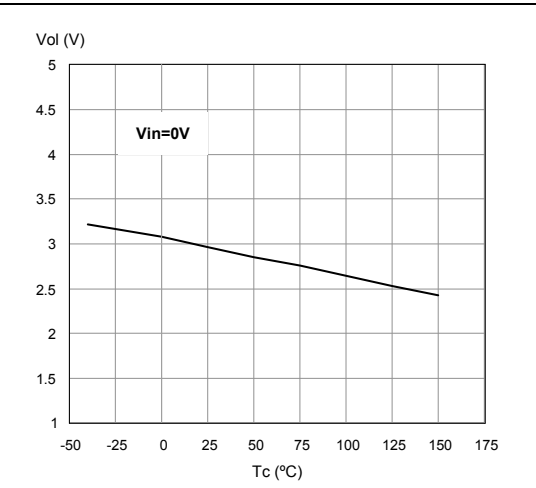


Figure 17. Input high level

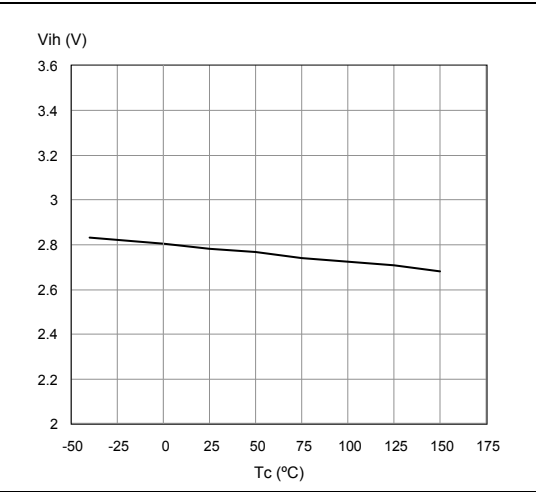


Figure 18. Input low level

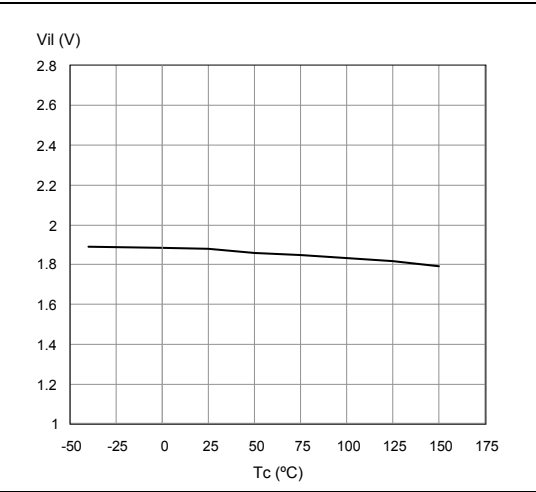


Figure 19. Turn-on voltage slope

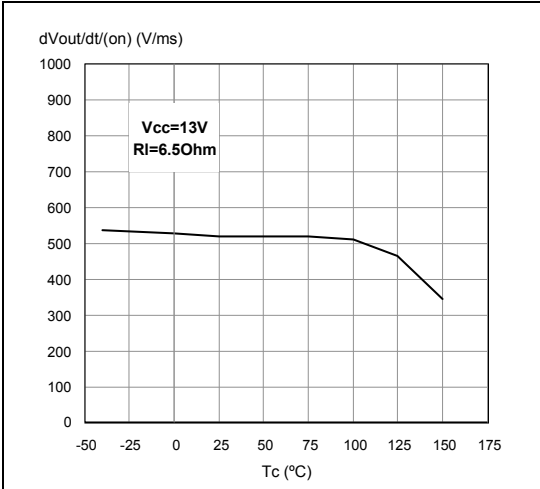


Figure 20. Turn-off voltage slope

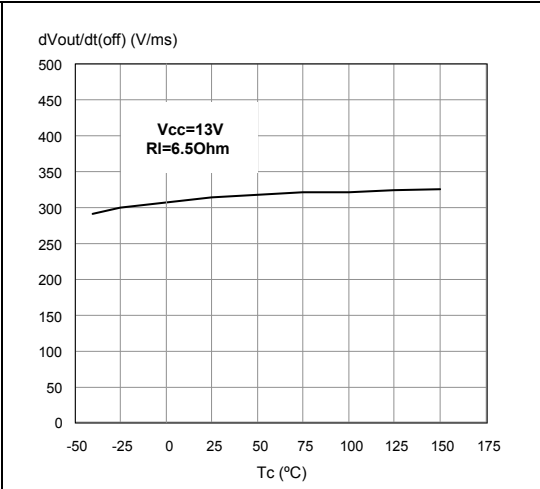


Figure 21. Overvoltage shutdown

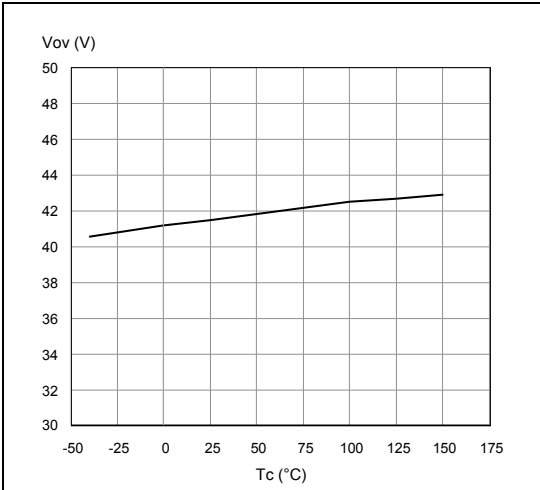


Figure 22.  $I_{lim}$  vs  $T_{case}$

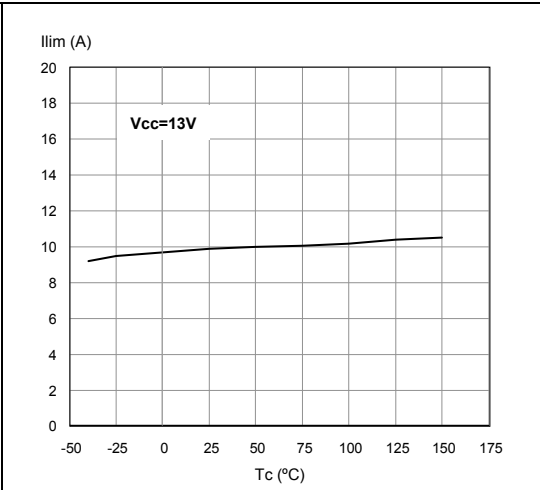


Figure 23. Input hysteresis voltage

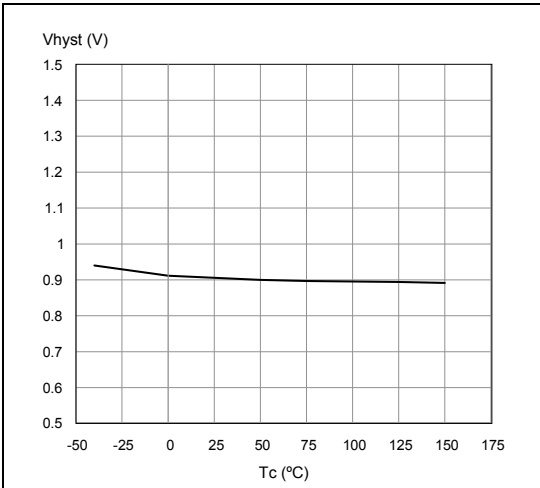
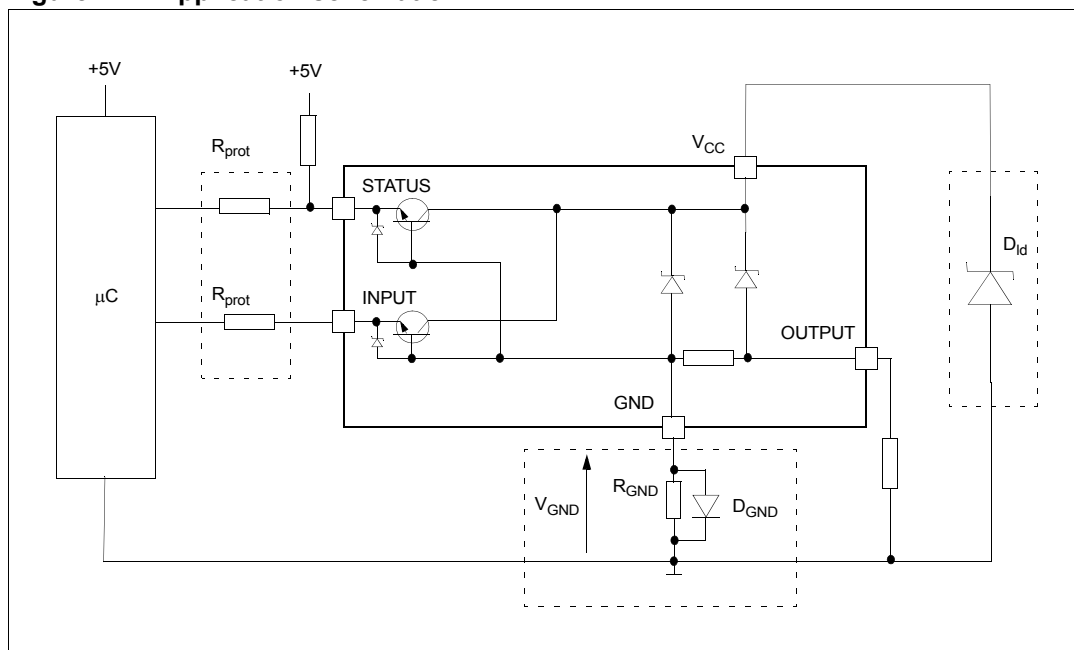


Figure 24. Application schematic



## 2.5 GND protection network against reverse battery

### 2.5.1 Solution 1: resistor in the ground line ( $R_{GND}$ only)

This can be used with any type of load.

The following is an indication on how to dimension the  $R_{GND}$  resistor.

1.  $R_{GND} \leq 600\text{mV} / (I_{S(on)max})$ .
2.  $R_{GND} \geq (-V_{CC}) / (-I_{GND})$

where  $-I_{GND}$  is the DC reverse ground pin current and can be found in the absolute maximum rating section of the device datasheet.

Power Dissipation in  $R_{GND}$  (when  $V_{CC} < 0$ : during reverse battery situations) is:

$$P_D = (-V_{CC})^2 / R_{GND}$$

This resistor can be shared amongst several different HSDs. Please note that the value of this resistor should be calculated with formula (1) where  $I_{S(on)max}$  becomes the sum of the maximum on-state currents of the different devices.

Please note that if the microprocessor ground is not shared by the device ground then the  $R_{GND}$  produces a shift ( $I_{S(on)max} * R_{GND}$ ) in the input thresholds and the status output values. This shift varies depending on how many devices are ON in the case of several high side drivers sharing the same  $R_{GND}$ .

If the calculated power dissipation leads to a large resistor or several devices have to share the same resistor then ST suggests to utilize Solution 2 (see below).

## 2.5.2 Solution 2: diode ( $D_{GND}$ ) in the ground line

A resistor ( $R_{GND}=1\text{ k}\Omega$ ) should be inserted in parallel to  $D_{GND}$  if the device drives an inductive load.

This small signal diode can be safely shared amongst several different HSDs. Also in this case, the presence of the ground network produces a shift ( $\approx 600\text{mV}$ ) in the input threshold and in the status output values if the microprocessor ground is not common to the device ground. This shift not varies if more than one HSD shares the same diode/resistor network.

Series resistor in input and status lines are also required to prevent that, during battery voltage transient, the current exceeds the absolute maximum rating.

Safest configuration for unused input and status pin is to leave them unconnected.

## 2.6 Load dump protection

$D_{ld}$  is necessary (voltage transient suppressor) if the load dump peak voltage exceeds the  $V_{CC}$  max DC rating. The same applies if the device is subject to transients on the  $V_{CC}$  line that are greater than the ones shown in the ISO T/R 7637/1 table.

## 2.7 Microcontroller I/Os protection

If a ground protection network is used and negative transient are present on the  $V_{CC}$  line, the control pins is pulled negative. ST suggests to insert a resistor ( $R_{prot}$ ) in line to prevent the  $\mu C$  I/Os pins to latch-up.

The value of these resistors is a compromise between the leakage current of  $\mu C$  and the current required by the HSD I/Os (Input levels compatibility) with the latch-up limit of  $\mu C$  I/Os.

$$-V_{CCpeak}/I_{latchup} \leq R_{prot} \leq (V_{OH\mu C} - V_{IH} - V_{GND}) / I_{IHmax}$$

Calculation example:

For  $V_{CCpeak} = -100\text{ V}$  and  $I_{latchup} \geq 20\text{ mA}$ ;  $V_{OH\mu C} \geq 4.5\text{ V}$

$$5\text{ k}\Omega \leq R_{prot} \leq 65\text{ k}\Omega.$$

Recommended values:  $R_{prot} = 10\text{ k}\Omega$ .

## 2.8 Open-load detection in off-state

Off-state open-load detection requires an external pull-up resistor ( $R_{PU}$ ) connected between output pin and a positive supply voltage ( $V_{PU}$ ) like the +5 V line used to supply the microprocessor.

The external resistor has to be selected according to the following requirements:

1. no false open-load indication when load is connected: in this case we have to avoid  $V_{OUT}$  to be higher than  $V_{OLmin}$ ; this results in the following condition  

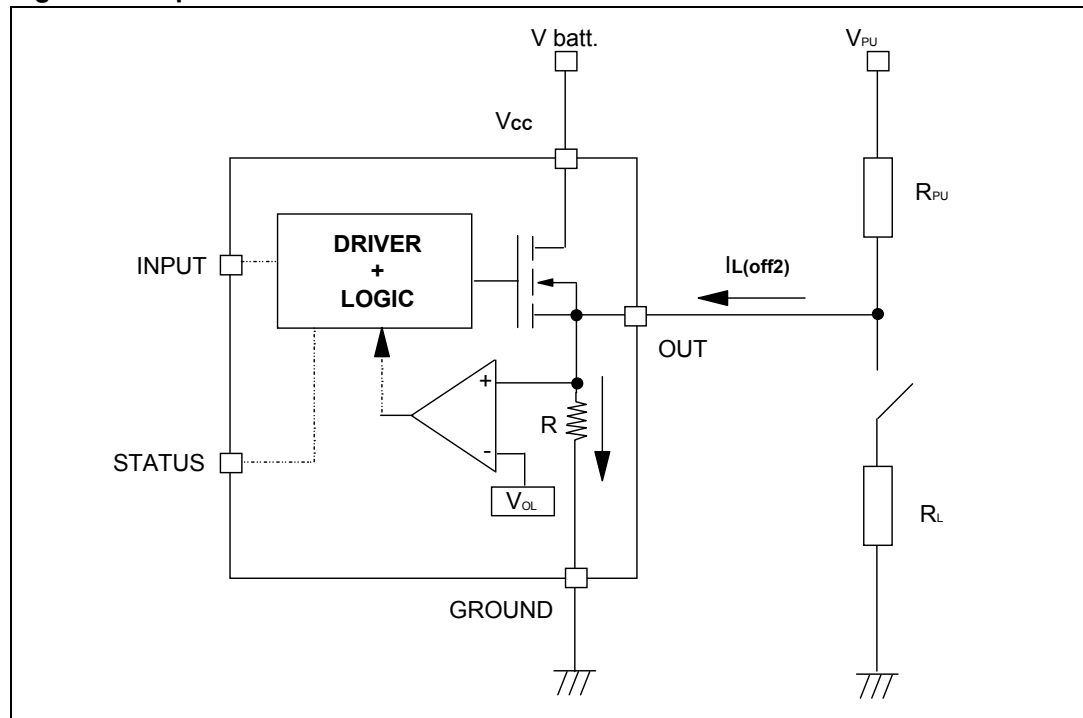
$$V_{OUT} = (V_{PU} / (R_L + R_{PU})) R_L < V_{OLmin}.$$
2. no misdetection when load is disconnected: in this case the  $V_{OUT}$  has to be higher than  $V_{OLmax}$ ; this results in the following condition  $R_{PU} < (V_{PU} - V_{OLmax}) / I_{L(off2)}.$



Because  $I_{S(OFF)}$  may significantly increase if  $V_{out}$  is pulled high (up to several mA), the pull-up resistor  $R_{PU}$  should be connected to a supply that is switched off when the module is in standby.

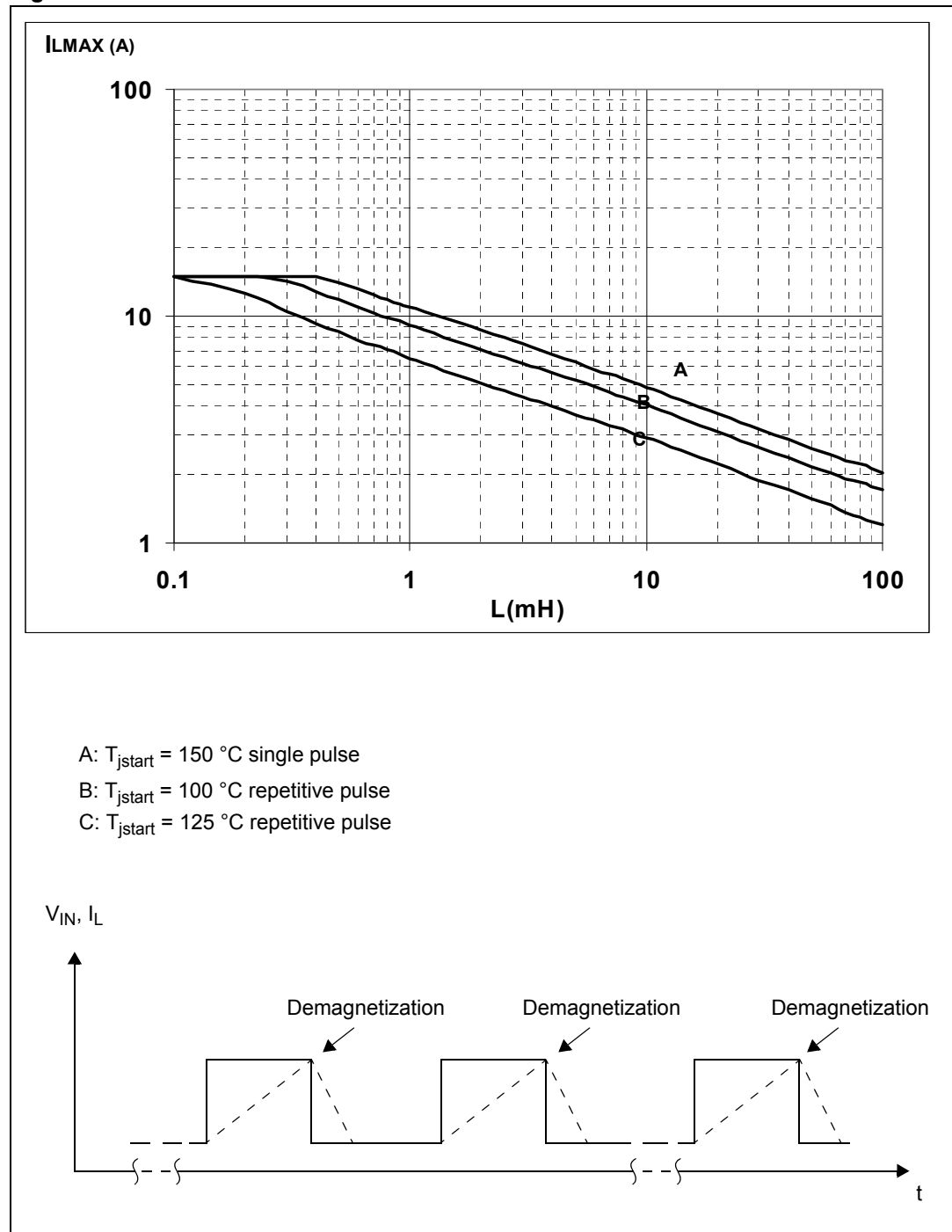
The values of  $V_{OLmin}$ ,  $V_{OLmax}$  and  $I_{L(off2)}$  are available in the electrical characteristics section.

**Figure 25. Open-load detection in off-state**



## 2.9 SO-8 maximum demagnetization energy ( $V_{CC} = 13.5\text{ V}$ )

Figure 26. SO-8 maximum turn-off current versus inductance

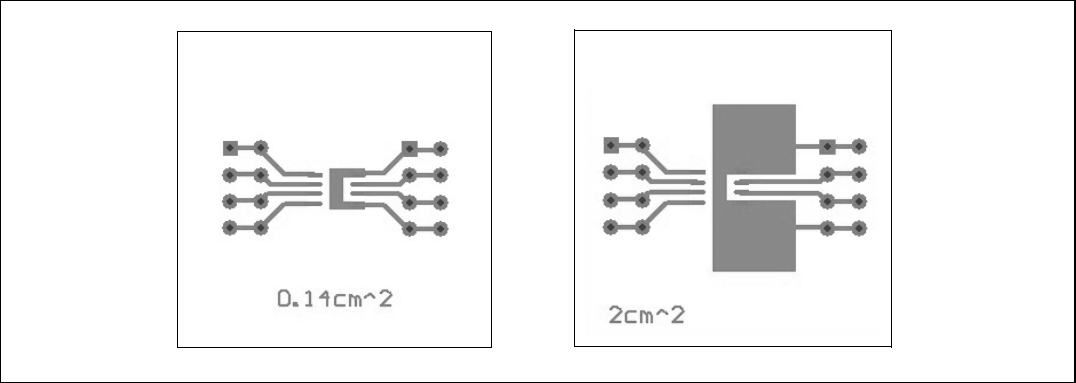


Note: Values are generated with  $R_L = 0\text{ }\Omega$ . In case of repetitive pulses,  $T_{jstart}$  (at beginning of each demagnetization) of every pulse must not exceed the temperature specified above for curves B and C.

### 3 Package and PCB thermal data

#### 3.1 SO-8 thermal data

Figure 27. SO-8 PC board



Note: Layout condition of  $R_{th}$  and  $Z_{th}$  measurements (PCB FR4 area = 58 mm x 58 mm, PCB thickness = 2 mm, Cu thickness=35  $\mu\text{m}$ , Copper areas: 0.14  $\text{cm}^2$ , 2  $\text{cm}^2$ ).

Figure 28.  $R_{thj-amb}$  vs PCB copper area in open box free air condition

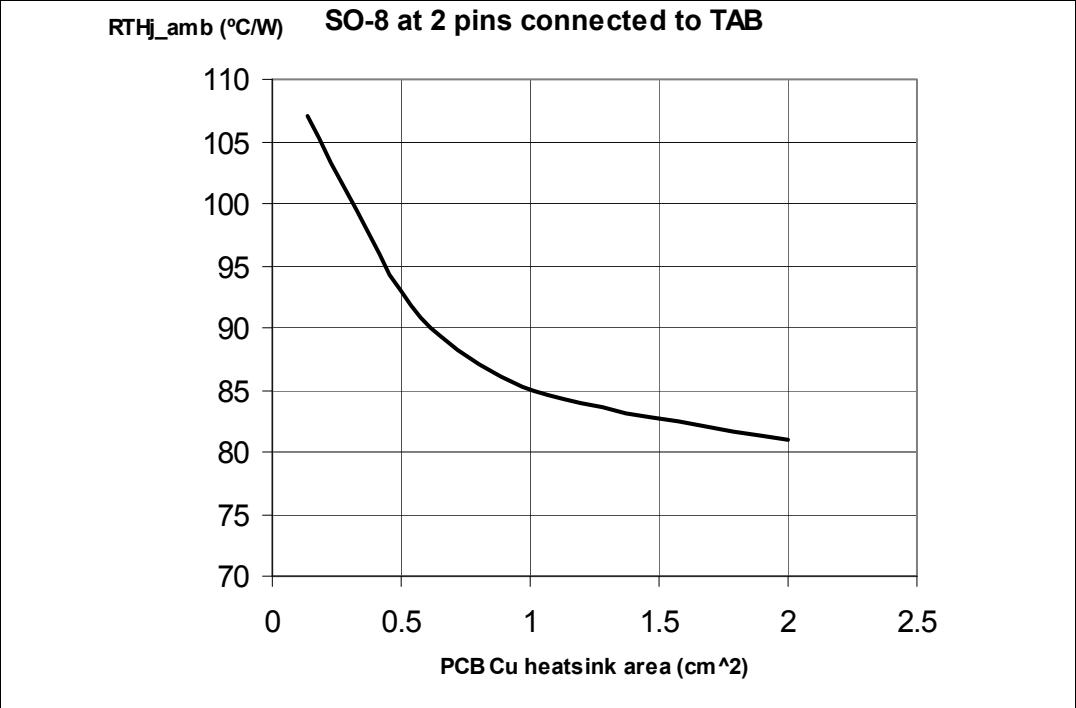
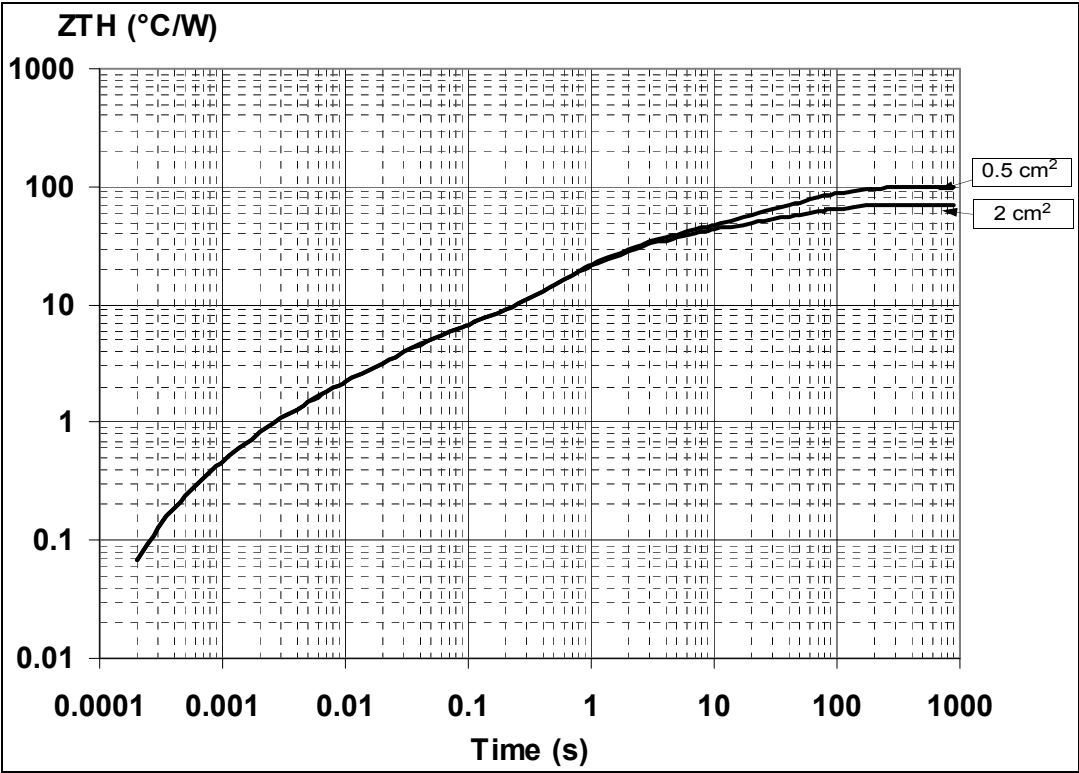


Figure 29. SO-8 thermal impedance junction ambient single pulse



Equation 1: pulse calculation formula

$$Z_{TH\delta} = R_{TH} \cdot \delta + Z_{THtp}(1 - \delta)$$

where  $\delta = t_p/T$

Figure 30. SO-8 thermal fitting model of a single channel

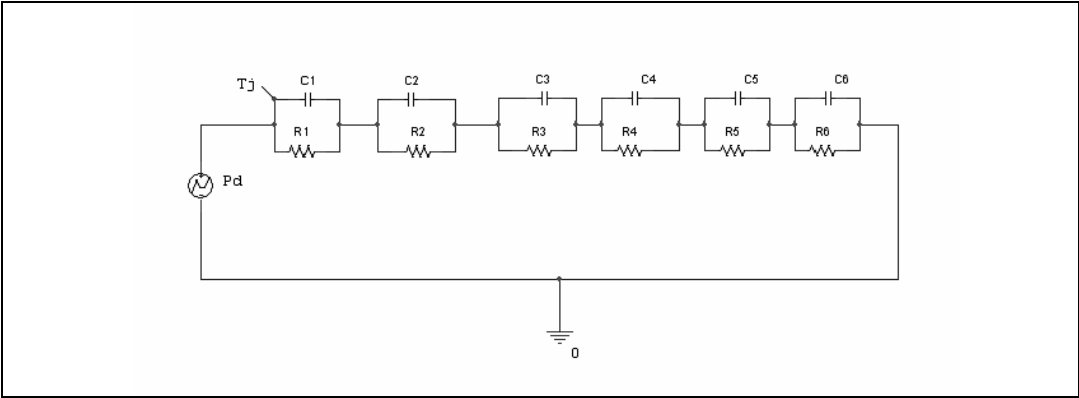


Table 16. SO-8 thermal parameter

| Area/island (cm <sup>2</sup> ) | 0.5  | 2 |
|--------------------------------|------|---|
| R1 (°C/W)                      | 0.05 |   |
| R2 (°C/W)                      | 0.8  |   |
| R3 (°C/W)                      | 3.5  |   |

Table 16. SO-8 thermal parameter (continued)

| Area/island (cm <sup>2</sup> ) | 0.5      | 2  |
|--------------------------------|----------|----|
| R4 (°C/W)                      | 21       |    |
| R5 (°C/W)                      | 16       |    |
| R6 (°C/W)                      | 58       | 28 |
| C1 (W·s/°C)                    | 0.006    |    |
| C2 (W·s/°C)                    | 2.60E-03 |    |
| C3 (W·s/°C)                    | 0.0075   |    |
| C4 (W·s/°C)                    | 0.045    |    |
| C5 (W·s/°C)                    | 0.35     |    |
| C6 (W·s/°C)                    | 1.05     | 2  |

## 4 Package and packing information

### 4.1 ECOPACK® packages

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com).

ECOPACK® is an ST trademark.

### 4.2 SO-8 mechanical data

Figure 31. SO-8 package dimensions

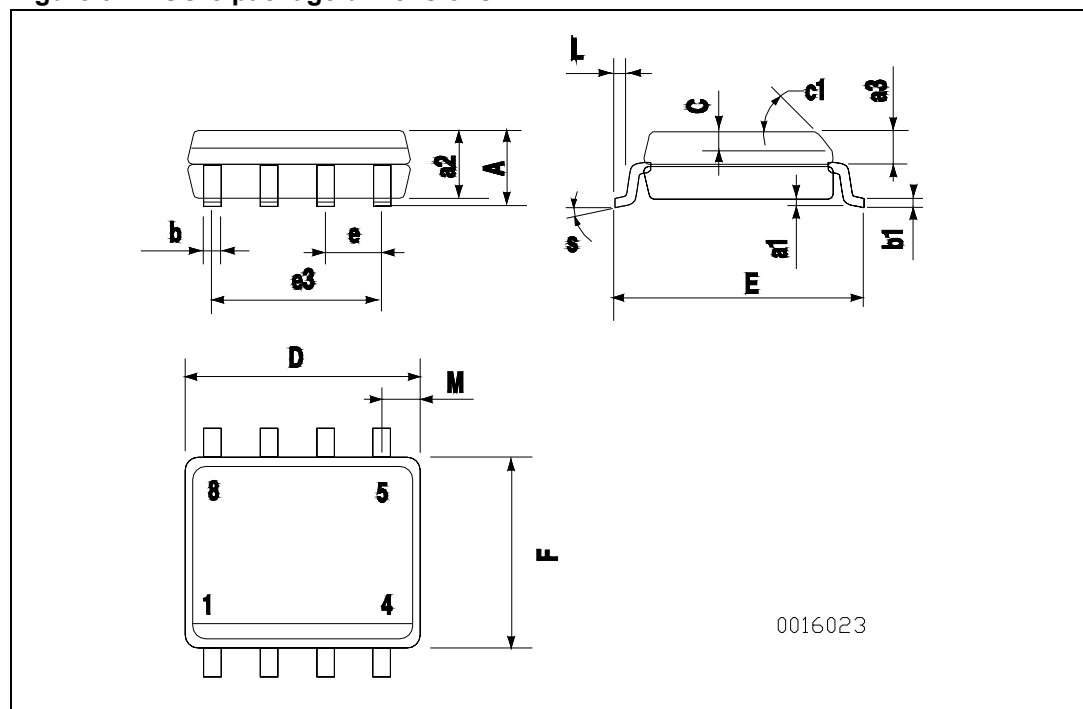


Table 17. SO-8 mechanical data

| Dim. | Millimeter |      |      |
|------|------------|------|------|
|      | Min.       | Typ. | Max. |
| A    |            |      | 1.75 |
| a1   | 0.1        |      | 0.25 |
| a2   |            |      | 1.65 |
| a3   | 0.65       |      | 0.85 |
| b    | 0.35       |      | 0.48 |
| b1   | 0.19       |      | 0.25 |

Table 17. SO-8 mechanical data (continued)

| Dim. | Millimeter |      |      |
|------|------------|------|------|
|      | Min.       | Typ. | Max. |
| C    | 0.25       |      | 0.5  |
| c1   | 45 (typ.)  |      |      |
| D    | 4.8        |      | 5    |
| E    | 5.8        |      | 6.2  |
| e    |            | 1.27 |      |
| e3   |            | 3.81 |      |
| F    | 3.8        |      | 4    |
| L    | 0.4        |      | 1.27 |
| M    |            |      | 0.6  |
| S    | 8 (max.)   |      |      |
| L1   | 0.8        |      | 1.2  |

### 4.3 Packing information

Figure 32. SO-8 tube shipment (no suffix)

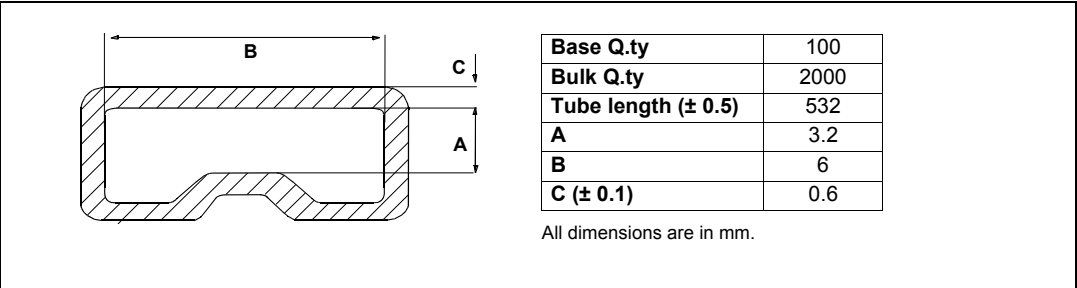
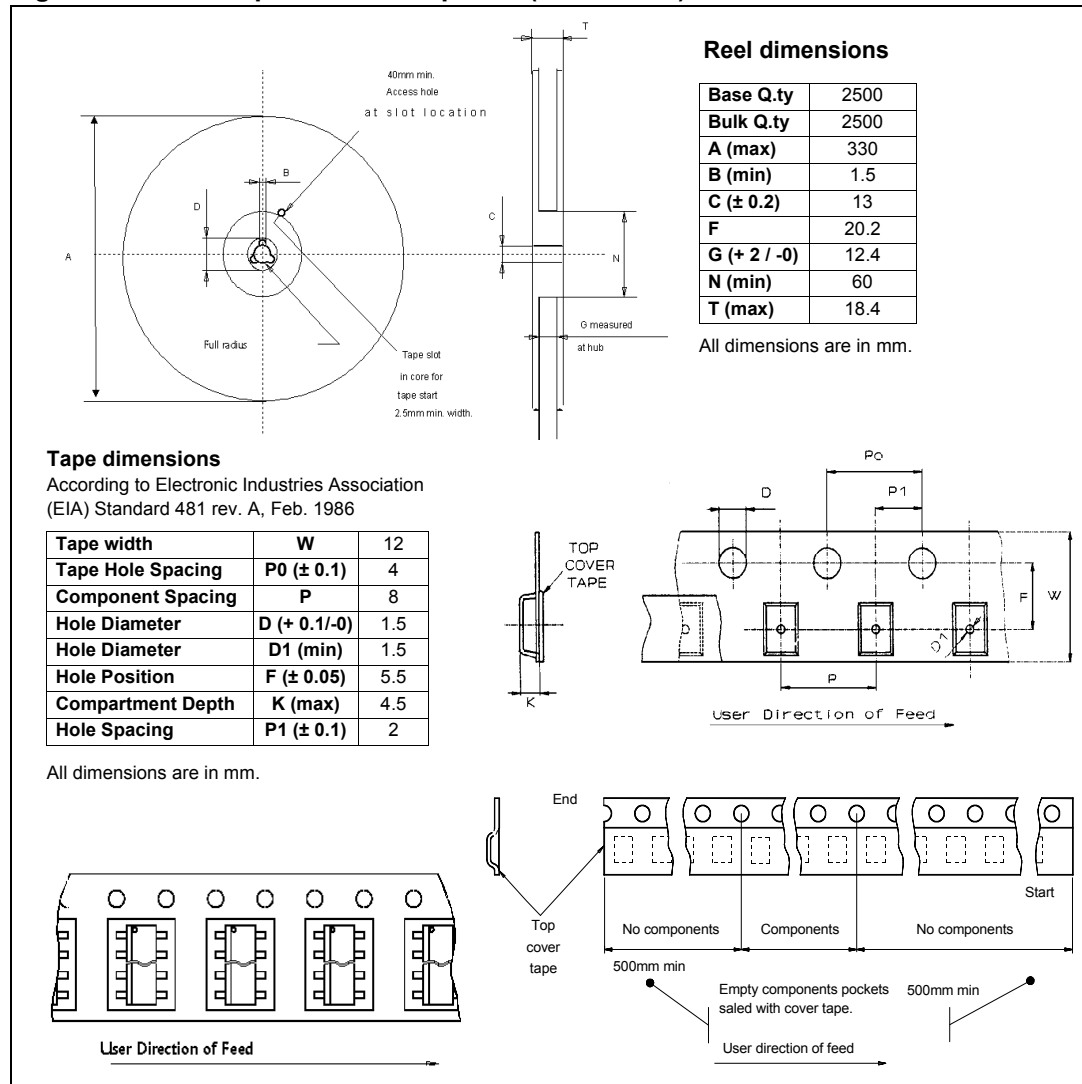


Figure 33. SO-8 tape and reel shipment (suffix "TR")





## 5 Revision history

**Table 18. Document revision history**

| Date        | Revision | Changes             |
|-------------|----------|---------------------|
| 18-Nov-2009 | 1        | Initial release.    |
| 20-Sep-2013 | 2        | Updated Disclaimer. |

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